

60 V, 1 A NPN/PNP low VCEsat transistor

3 March 2025

1. General description

NPN/PNP low V_{CEsat} transistor pair in a SOT457 (SC-74) Surface Mounted Device (SMD) plastic package.

2. Features and benefits

- Low collector-emitter saturation voltage V_{CEsat}
- + High collector current capability: ${\rm I}_{\rm C}$ and ${\rm I}_{\rm CM}$
- + High collector current gain (h_{FE}) at high I_C
- · High efficiency due to less heat generation
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors
- AEC-Q101 qualified

3. Applications

- Complementary MOSFET driver
- Half and full bridge motor drivers
- Dual low power switches (e.g. motors, fans)
- Automotive applications

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	tor unless otherwise spec	fied; for the PNP transistor with nega	tive pola	arity			
V _{CEO}	collector-emitter voltage	open base		-	-	60	V
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	2	А
TR1 (NPN)		1					
I _C	collector current		[1]	-	-	1	А
R _{CEsat}	collector-emitter saturation resistance	I_{C} = 1 A; I_{B} = 100 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		-	200	250	mΩ
TR2 (PNP)		1					_
I _C	collector current		[1]	-	-	-900	mA
R _{CEsat}	collector-emitter saturation resistance	I_{C} = -1 A; I_{B} = -100 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		-	250	330	mΩ

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

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5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1		C1 B2 E2
2	B1	base TR1		
3	C2	collector TR2		
4	E2	emitter TR2		
5	B2	base TR2	TSOP6 (SOT457)	 E1 B1 C2
6	C1	collector TR1		sym139

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PBSS4160DPN	TSOP6	plastic, surface-mounted package (SC-74; TSOP6); 6 leads	<u>SOT457</u>		

7. Marking

Table 4. Marking codes

Type number	Marking code
PBSS4160DPN	B4

8. Limiting values

Table 5. Limiting values

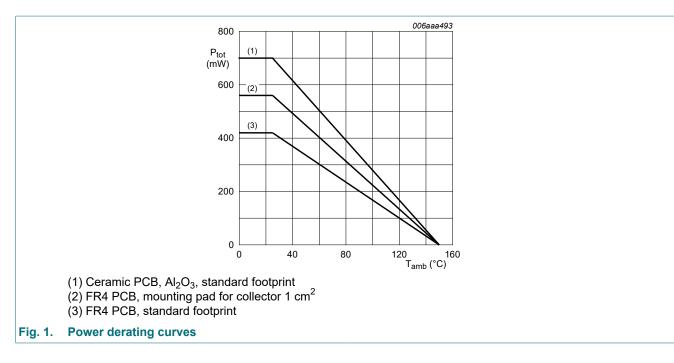
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
Per transist	or unless otherwise specified	; for the PNP transistor with neg	ative polarity			
V _{CBO}	collector-base voltage	open emitter		-	80	V
V _{CEO}	collector-emitter voltage	open base		-	60	V
V _{EBO}	emitter-base voltage	open collector		-	5	V
I _C	collector current		[1]	-	1	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	2	А
I _B	base current			-	300	mA
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms		-	1	А
P _{tot} total power dissipation	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	290	mW
			[3]	-	370	mW
		[1]	-	450	mW	
TR1 (NPN)						
I _C	collector current		[2]	-	870	mA
			[3]	-	1	А
TR2 (PNP)						
I _C	collector current		[2]	-	-770	mA
			[3]	-	-900	mA
Per device						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	420	mW
			[3]	-	560	mW
			[1]	-	700	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

[1]

Device mounted on a ceramic PCB, Al_2O_3 , standard footprint. Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint. Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm². [2] [3]

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9. Thermal characteristics

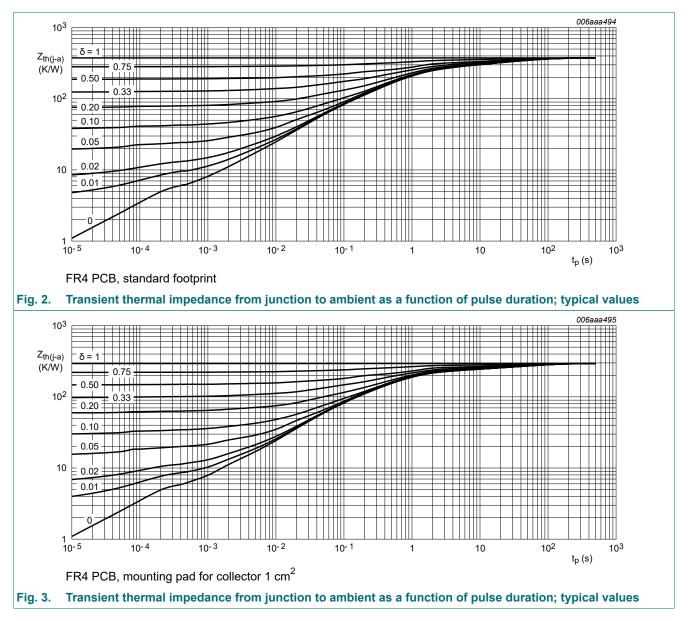
Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor			I				
R _{th(j-a)} thermal resistance from junction to ambient			[1]	-	-	431	K/W
	junction to ambient		[2]	-	-	338	K/W
	-	[3]	-	-	278	K/W	
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	105	K/W

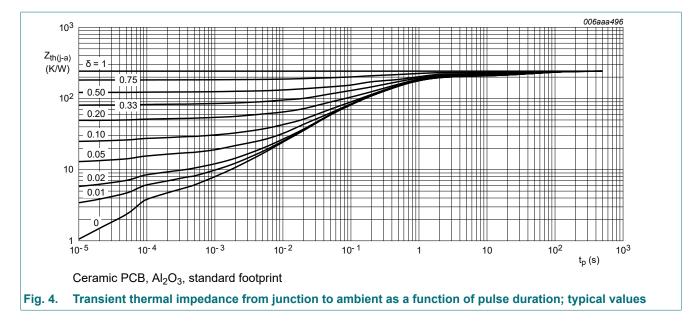
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².

[3] Device mounted on a ceramic PCB, \tilde{Al}_2O_3 , standard footprint.



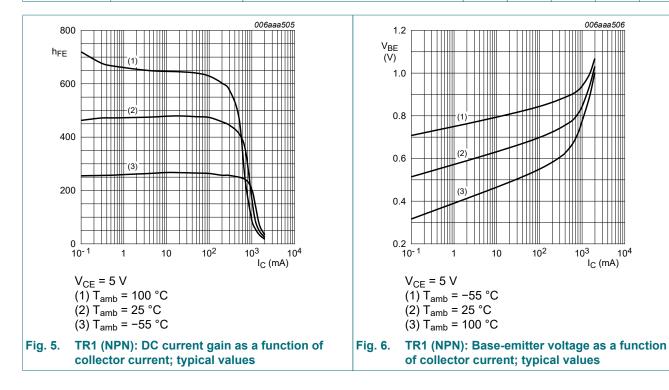
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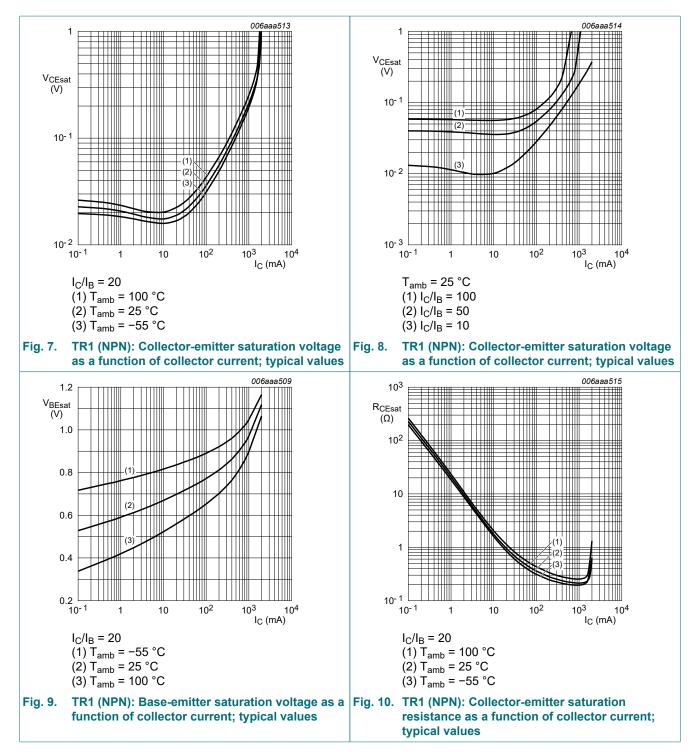


10. Characteristics

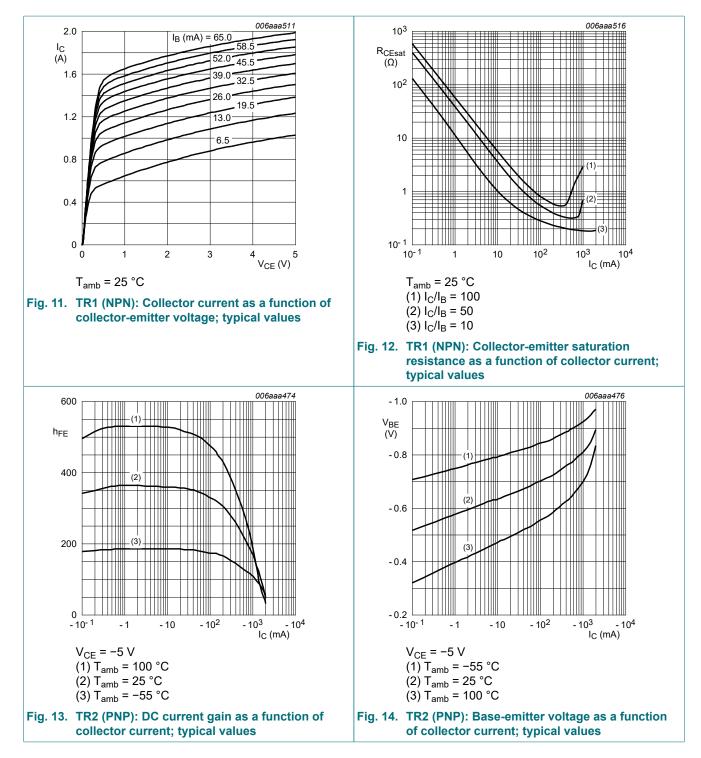
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Per transist	or unless otherwise specif	ied; for the PNP transistor with negative	e polarity			
I _{CBO}	collector-base cut-off	V _{CB} = 60 V; I _E = 0 A; T _{amb} = 25 °C	-	-	100	nA
	current	$V_{CB} = 60 \text{ V}; \text{ I}_{E} = 0 \text{ A}; \text{ T}_{i} = 150 ^{\circ}\text{C}$	-	-	50	μA
I _{CES}	collector-emitter cut-off current	$V_{CE} = 60 \text{ V}; \text{ V}_{BE} = 0 \text{ V}; \text{ T}_{amb} = 25 \text{ °C}$	-	-	100	nA
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}; \text{ T}_{amb} = 25 ^{\circ}\text{C}$	-	-	100	nA
TR1 (NPN)						
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 1 mA; T _{amb} = 25 °C	250	500	-	
		V_{CE} = 5 V; I _C = 500 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	200	420	-	
			100	180	-	
V _{CEsat}	collector-emitter	I _C = 100 mA; I _B = 1 mA; T _{amb} = 25 °C	-	90	110	mV
	saturation voltage	I _C = 500 mA; I _B = 50 mA; T _{amb} = 25 °C	-	115	140	mV
		I_{C} = 1 A; I_{B} = 100 mA; pulsed; $t_{p} \le$	-	200	250	mV
R _{CEsat}	collector-emitter saturation resistance	300 μs; δ ≤ 0.02; T _{amb} = 25 °Ċ	-	200	250	mΩ
V _{BEsat}	base-emitter saturation voltage	I _C = 1 A; I _B = 50 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	0.95	1.1	V
V _{BEon}	base-emitter turn-on voltage	$ \begin{array}{l} V_{CE} = 5 \; V; \; I_{C} = 1 \; A; \; pulsed; \; t_{p} \leq \; 300 \; \mu s; \\ \delta \leq \; 0.02; \; T_{amb} = 25 \; ^{\circ} C \end{array} $	-	0.82	0.9	V
t _d	delay time	I _C = 0.5 A; I _{Bon} = 25 mA; I _{Boff} = -25 mA;	-	11	-	ns
t _r	rise time	T _{amb} = 25 °C	-	78	-	ns
t _{on}	turn-on time		-	90	-	ns
t _s	storage time		-	340	-	ns
t _f	fall time		-	160	-	ns
t _{off}	turn-off time		-	500	-	ns
f _T	transition frequency	V _{CE} = 10 V; I _C = 50 mA; f = 100 MHz; T _{amb} = 25 °C	150	220	-	MHz
C _c	collector capacitance	V _{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	5.5	10	pF
TR2 (PNP)			·		·	
h _{FE}	DC current gain	V_{CE} = -5 V; I _C = -1 mA; T _{amb} = 25 °C	200	350	-	
		V_{CE} = -5 V; I _C = -500 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	150	250	-	
		V_{CE} = -5 V; I _C = -1 A; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	100	160	-	
V _{CEsat}	collector-emitter	I _C = -100 mA; I _B = -1 mA; T _{amb} = 25 °C	-	-110	-165	mV
	saturation voltage	I_{C} = -500 mA; I_{B} = -50 mA; T_{amb} = 25 °C	-	-120	-175	mV
		I_{C} = -1 A; I_{B} = -100 mA; pulsed; $t_{p} \le$	-	-250	-330	mV
R _{CEsat}	collector-emitter saturation resistance	300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	250	330	mΩ

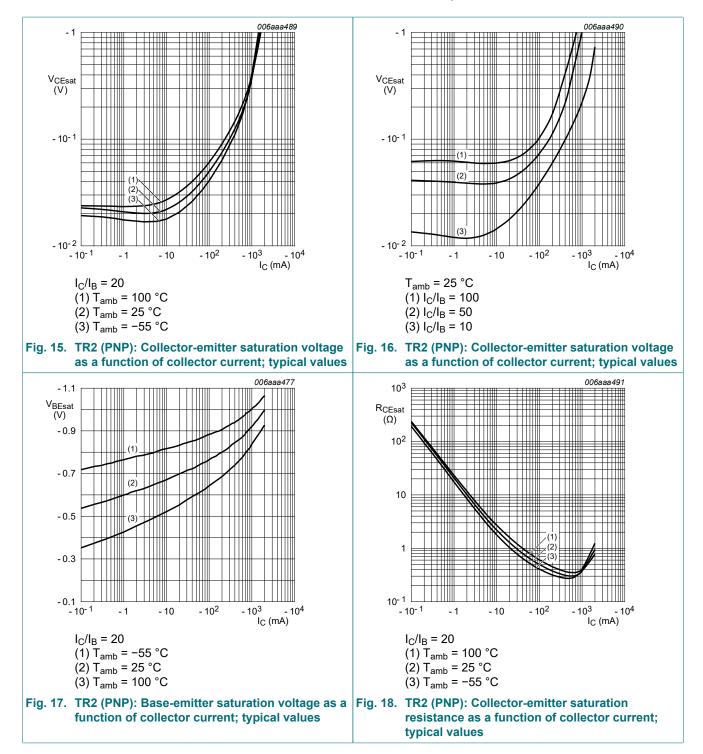
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{BEsat}	base-emitter saturation voltage	I _C = -1 A; I _B = -50 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C		-	-0.95	-1.1	V
V _{BEon}	base-emitter turn-on voltage	V _{CE} = -5 V; I _C = -1 A; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C		-	-0.82	-0.9	V
t _d	delay time	I _C = -0.5 A; I _{Bon} = -25 mA; I _{Boff} = 25 mA;		-	11	-	ns
t _r	rise time	T _{amb} = 25 °C		-	30	-	ns
t _{on}	turn-on time			-	41	-	ns
ts	storage time			-	205	-	ns
t _f	fall time			-	55	-	ns
t _{off}	turn-off time			-	260	-	ns
f _T	transition frequency	V _{CE} = -10 V; I _C = -50 mA; f = 100 MHz; T _{amb} = 25 °C		150	185	-	MHz
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C		-	9	15	pF



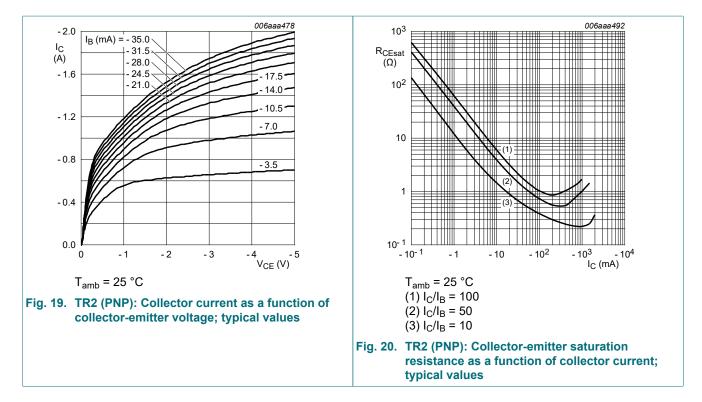


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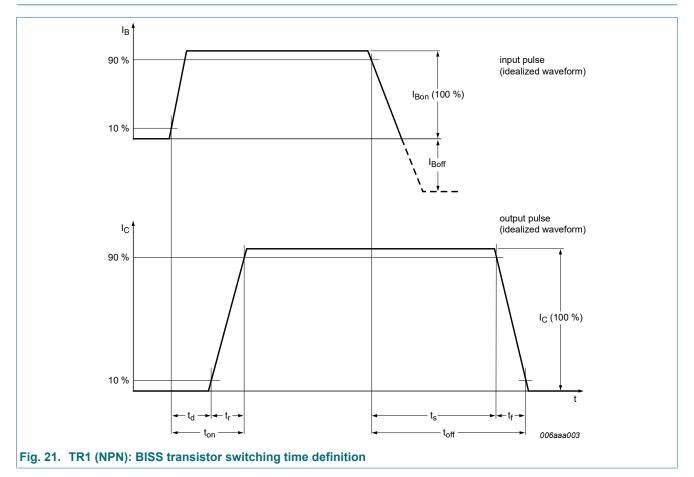


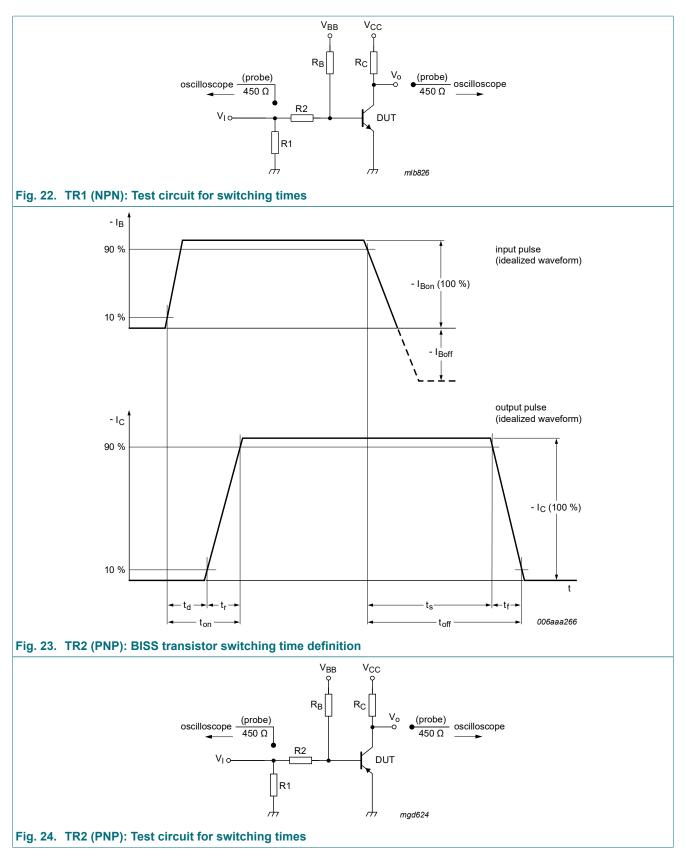


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11. Test information

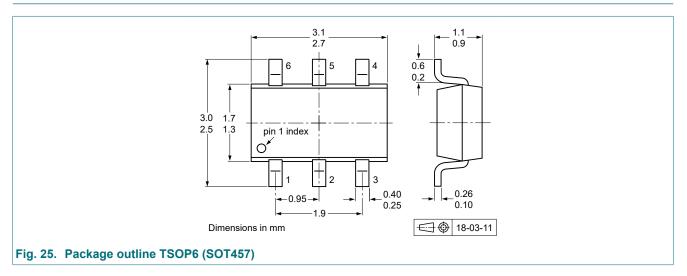




Quality information

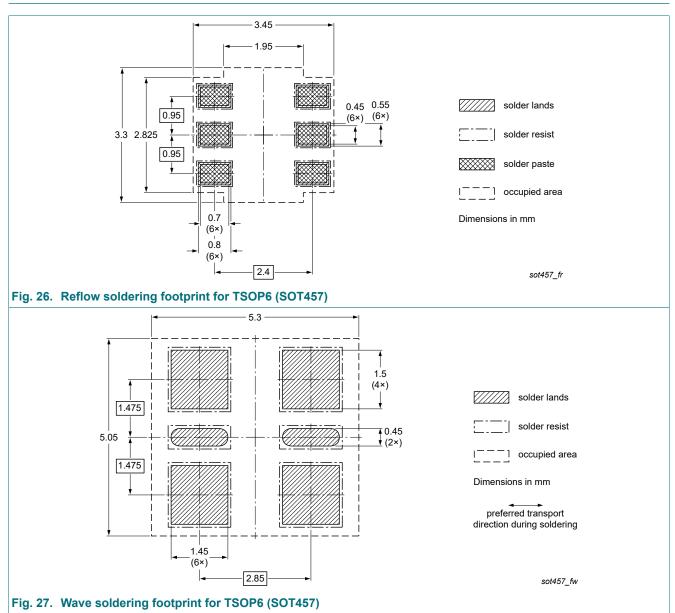
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



Product data sheet

14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PBSS4160DPN v.4	YYYYMMDD	Product data sheet		PBSS4160DPN_3			
Modifications:	Nexperia.Legal texts have been set to be the set of the set	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Section "Packing information" removed. 					
PBSS4160DPN_3	20091211	Product data sheet		PBSS4160DPN_2			
PBSS4160DPN_2	20050714	Product data sheet	-	PBSS4160DPN_1			
PBSS4160DPN_1	20040603	Objective data sheet	-	-			

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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